

# 2SC5813

### Silicon NPN epitaxial planar type

#### For DC-DC converter

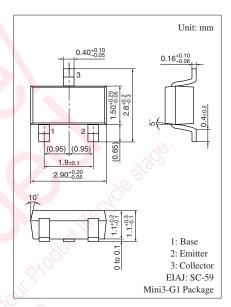
#### ■ Features

- ullet Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

#### ■ Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	80	V	
Collector-emitter voltage (Base open)	$V_{CEO}$	80	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	5	V	
Collector current	$I_{C}$	1.5	A	
Peak collector current	$I_{CP}$	3	A	
Collector power dissipation *	P <sub>C</sub>	600	mW	
Junction temperature	Tj	150	°C	
Storage temperature	$T_{stg}$	-55 to +150	°C	

Note) \*: Measure on the ceramic substrate at 15 mm  $\times$  15 mm  $\times$  0.6 mm



Marking Symbol: 5H

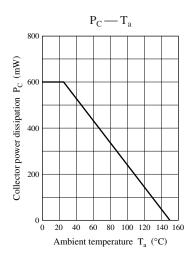
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

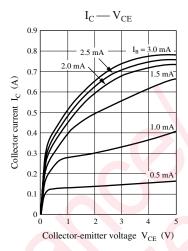
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 10 \mu{\rm A},  I_{\rm E} = 0$	80			V
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = 1 \text{ mA}, I_B = 0$	80			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = 10 \ \mu A, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 40 \text{ V}, I_{E} = 0$	,		0.1	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CE} = 2 \text{ V}, I_{C} = 100 \text{ mA}$	200			_
Collector-emitter saturation voltage *	V <sub>CE(sat)</sub>	$I_C = 1 \text{ A}, I_B = 20 \text{ mA}$		350	500	mV
Transition frequency	$f_T$	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		180		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		15	25	pF
(Common base, input open circuited)		Jeg Kink				

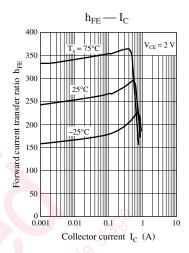
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

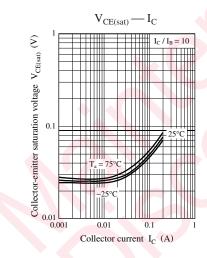
2. \*: Pulse measurement

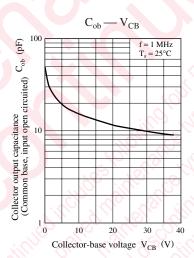
## **Panasonic**











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